

## Surface Mount Schottky Barrier Diode

**(Pb) Lead(Pb)-Free**

### Features:

- \* Ultra high-speed switching
- \* Very low forward voltage
- \* Voltage clampingProtection circuits.

**SCHOTTKY DIODE  
1.0 AMPERES  
20 VOLTS**



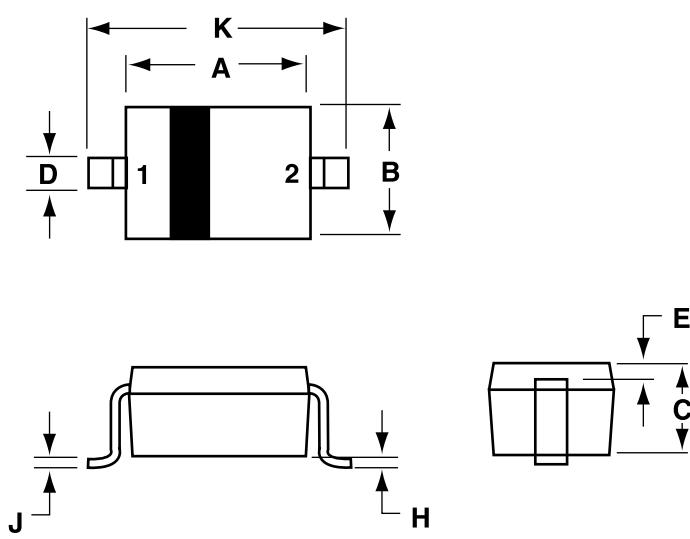
**SOD-323**

### Mechanical Data:

- \* Case: SOD-323
- \* Plastic Material –UL Recognition Flammability Classification 94V-O
- \* Leads: Solderable per MIL-STD-202, Method 208
- \* Polarity: Cathode Band
- \* Weight: 0.004 grams(approx.)

## SOD-323 Outline Demensions

Unit:mm



Dim	MILLIMETERS	
	Min	Max
<b>A</b>	1.60	1.80
<b>B</b>	1.15	1.35
<b>C</b>	0.80	1.00
<b>D</b>	0.25	0.40
<b>E</b>	0.15 REF	
<b>H</b>	0.00	0.10
<b>J</b>	0.089	0.177
<b>K</b>	2.30	2.70

PIN 1.CATHODE  
2.ANODE

**Maximum Ratings (T<sub>A</sub>=25°C Unless otherwise noted)**

Characteristic	Symbol	Value	Unit
Continuous Reverse Voltage	V <sub>R</sub>	20	V
Average Rectified Output Current	I <sub>O</sub>	1.0	A
Non-Repetitive Peak Forward Surge Current	I <sub>FSM</sub>	5.0	A
Thermal Resistance junction to Ambient	R <sub>θJA</sub>	220 <sup>1</sup> 180 <sup>2</sup>	°C/W °C/W
Operating Ambient temperature Range	T <sub>amb</sub>	-65 to +125	°C
Operating Temperature Range	T <sub>J</sub>	+125	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150	°C

1. Device mounted on an FR4 printed-circuit board with Cu clad 10x10mm.

2. Device mounted on an FR4 printed-circuit board with Cu clad 40x40mm

**Electrical Characteristics (T<sub>A</sub>=25°C Unless otherwise noted)**

Characteristic	Symbol	Min	Typ	Max	Unit
Forward Voltage I <sub>F</sub> =10mA I <sub>F</sub> =100mA I <sub>F</sub> =1000mA	V <sub>F</sub>	-	240 300 480	270 350 550	mV
Reverse Current V <sub>R</sub> =5V V <sub>R</sub> =8V V <sub>R</sub> =15V	I <sub>R</sub>	-	5 7 10	10 20 50	µA
Capacitance between terminals V <sub>R</sub> =5V, f=1.0MHz	C <sub>d</sub>	-	19	25	pF

**Device Marking**

Item	Marking	Equivalent Circuit diagram
B1020WS	V2	

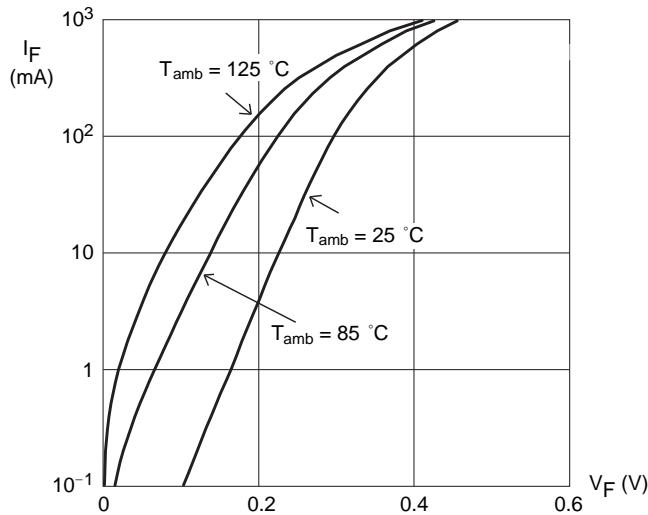
**Electrical Characteristic curves( $T_A=25^\circ C$ )**

Fig.1 Forward current as a function of forward

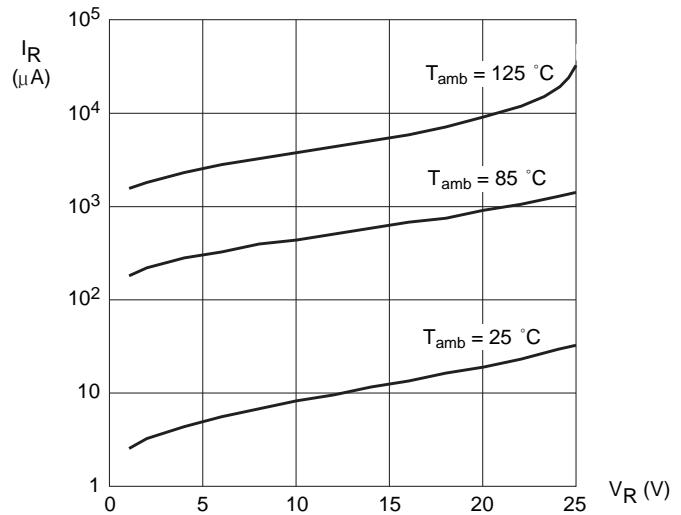


Fig.2 Reverse current as a function of reverse

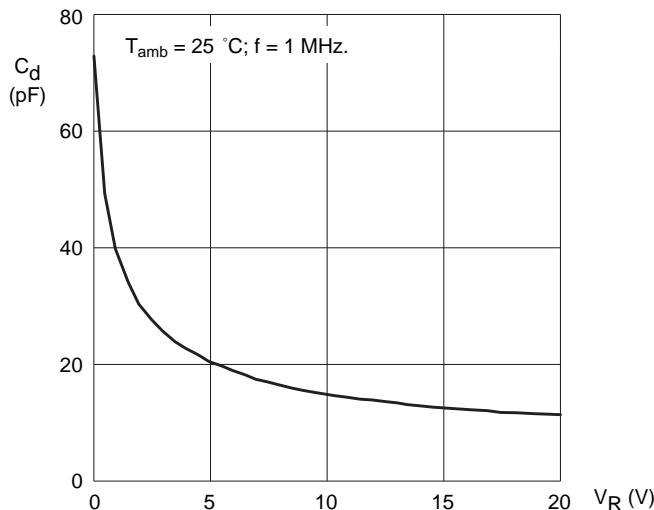


Fig.3 Diode capacitance as a function of reverse